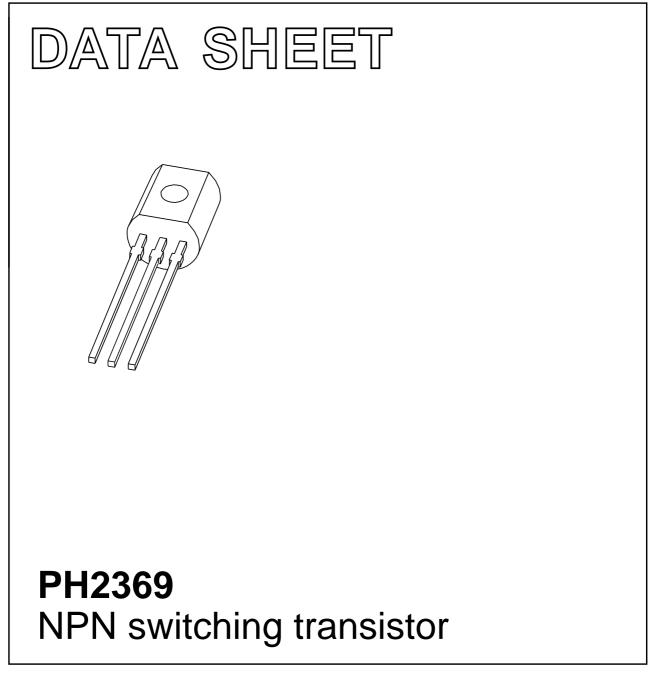
## DISCRETE SEMICONDUCTORS



Product specification Supersedes data of 1999 Apr 27 2004 Oct 11



#### FEATURES

- Low current (max. 200 mA)
- Low voltage (max. 15 V).

#### APPLICATIONS

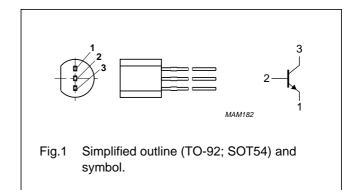
• High-speed switching.

#### DESCRIPTION

NPN switching transistor in a TO-92; SOT54 plastic package.

#### PINNING

PIN	DESCRIPTION	
1	emitter	
2	base	
3	collector	



#### **ORDERING INFORMATION**

		PACKAGE		
	NAME	DESCRIPTION	VERSION	
PH2369	SC-43A	plastic single-ended leaded (through hole) package; 3 leads		

#### LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V <sub>CBO</sub>	collector-base voltage	open emitter	-	40	V
V <sub>CEO</sub>	collector-emitter voltage	open base	-	15	V
V <sub>EBO</sub>	emitter-base voltage	open collector	-	4.5	V
I <sub>C</sub>	collector current (DC)		-	200	mA
I <sub>CM</sub>	peak collector current		-	300	mA
I <sub>BM</sub>	peak base current		-	100	mA
P <sub>tot</sub>	total power dissipation	$T_{amb} \le 25 \ ^{\circ}C$	-	500	mW
T <sub>stg</sub>	storage temperature		-65	+150	°C
Tj	junction temperature		_	150	°C
T <sub>amb</sub>	ambient temperature		-65	+150	°C

### PH2369

### PH2369

### THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
R <sub>th(j-a)</sub>	thermal resistance from junction to ambient	note 1	250	K/W

#### Note

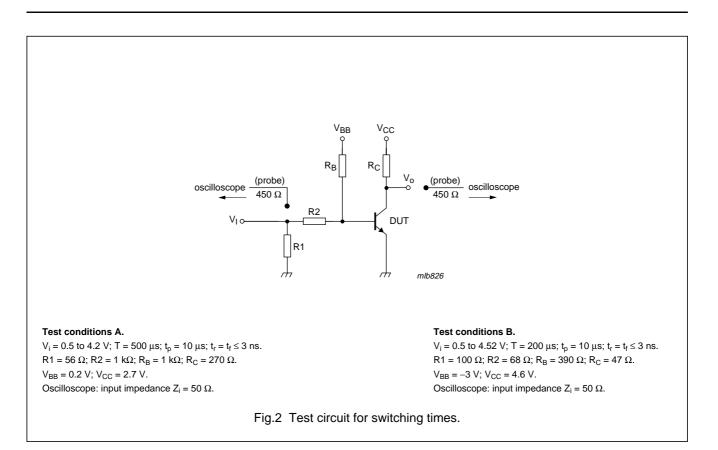
1. Transistor mounted on an FR4 printed-circuit board.

#### CHARACTERISTICS

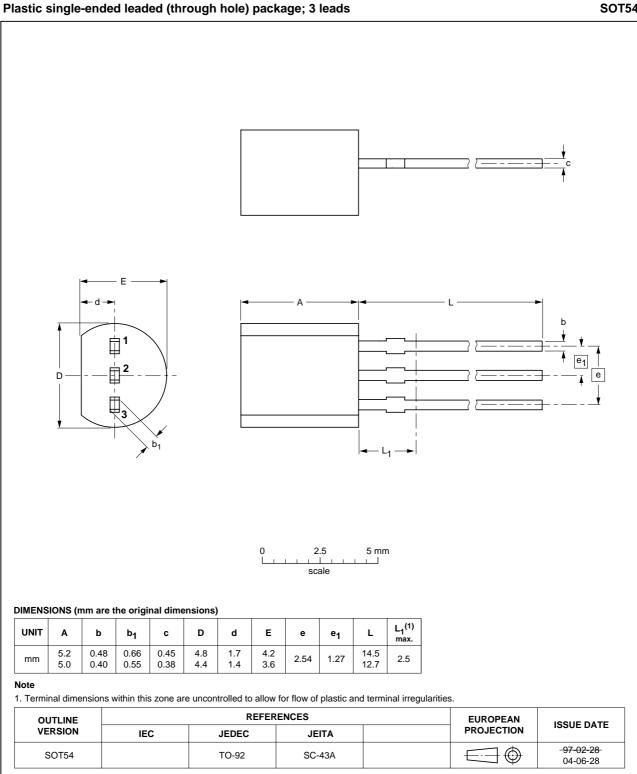
 $T_{amb}$  = 25 °C unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
I <sub>CBO</sub>	collector-base cut-off current	$V_{CB} = 20 \text{ V}; \text{ I}_{E} = 0 \text{ A}$	-	400	nA
		V <sub>CB</sub> = 20 V; I <sub>E</sub> = 0 A; T <sub>j</sub> = 125 °C	-	30	μA
I <sub>EBO</sub>	emitter-base cut-off current	$V_{EB} = 4 \text{ V}; I_{C} = 0 \text{ A}$	-	100	nA
h <sub>FE</sub>	DC current gain	V <sub>CE</sub> = 1 V; I <sub>C</sub> = 10 mA	40	120	
		$V_{CE} = 1 \text{ V}; \text{ I}_{C} = 10 \text{ mA}; \text{ T}_{amb} = -55 ^{\circ}\text{C}$	20	-	
		V <sub>CE</sub> = 2 V; I <sub>C</sub> = 100 mA	20	-	
V <sub>CEsat</sub>	collector-emitter saturation voltage	I <sub>C</sub> = 10 mA; I <sub>B</sub> = 1 mA	-	250	mV
V <sub>BEsat</sub>	base-emitter saturation voltage	I <sub>C</sub> = 10 mA; I <sub>B</sub> = 1 mA	700	850	mV
Cc	collector capacitance	V <sub>CB</sub> = 5 V; I <sub>E</sub> = i <sub>e</sub> = 0 A; f = 1 MHz	-	4	pF
C <sub>e</sub>	emitter capacitance	$V_{EB} = 1 \text{ V}; I_{C} = i_{c} = 0 \text{ A}; f = 1 \text{ MHz}$	-	4.5	pF
f <sub>T</sub>	transition frequency	V <sub>CE</sub> = 10 V; I <sub>C</sub> = 10 mA; f = 100 MHz	500	-	MHz
Switching t	imes (between 10 % and 90 % leve	ls)			
t <sub>on</sub>	turn-on time	I <sub>Con</sub> = 10 mA; I <sub>Bon</sub> = 3 mA; I <sub>Boff</sub> = -1.5 mA; see Fig.2 test conditions A		10	ns
t <sub>d</sub>	delay time			4	ns
t <sub>r</sub>	rise time			6	ns
t <sub>off</sub>	turn-off time			20	ns
ts	storage time			10	ns
t <sub>f</sub>	fall time			10	ns
t <sub>on</sub>	turn-on time	$I_{Con} = 100 \text{ mA}; I_{Bon} = 40 \text{ mA}; I_{Boff} = -20 \text{ mA};$	-	13	ns
t <sub>off</sub>	turn-off time	see Fig.2 test conditions B		35	ns

### PH2369



#### PACKAGE OUTLINE



PH2369

SOT54

PH2369

#### DATA SHEET STATUS

LEVEL	DATA SHEET STATUS <sup>(1)</sup>	PRODUCT STATUS <sup>(2)(3)</sup>	DEFINITION
I	Objective data	Development	This data sheet contains data from the objective specification for product development. Philips Semiconductors reserves the right to change the specification in any manner without notice.
11	Preliminary data	Qualification	This data sheet contains data from the preliminary specification. Supplementary data will be published at a later date. Philips Semiconductors reserves the right to change the specification without notice, in order to improve the design and supply the best possible product.
	Product data	Production	This data sheet contains data from the product specification. Philips Semiconductors reserves the right to make changes at any time in order to improve the design, manufacturing and supply. Relevant changes will be communicated via a Customer Product/Process Change Notification (CPCN).

#### Notes

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- 2. The product status of the device(s) described in this data sheet may have changed since this data sheet was published. The latest information is available on the Internet at URL http://www.semiconductors.philips.com.
- 3. For data sheets describing multiple type numbers, the highest-level product status determines the data sheet status.

#### DEFINITIONS

**Short-form specification** — The data in a short-form specification is extracted from a full data sheet with the same type number and title. For detailed information see the relevant data sheet or data handbook.

Limiting values definition — Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 60134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

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